

FEATURES

- *Guaranteed* 10 ppm / °C temperature coefficient
- *Guaranteed* 1.0Ω max. dynamic impedance
- *Guaranteed* 20µV max. wideband noise
- Wide operating current range 0.6mA to 15mA

APPLICATIONS

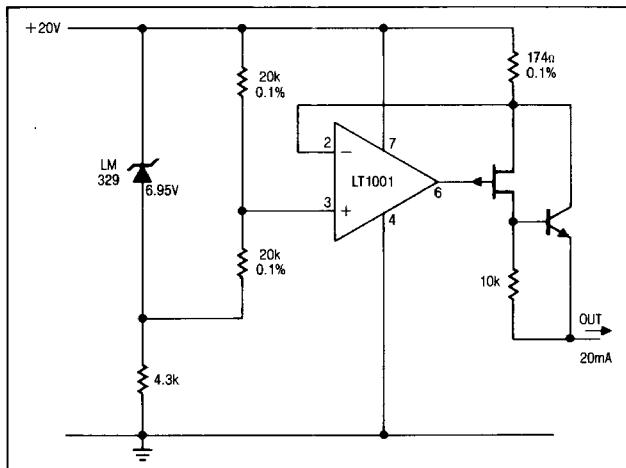
- Transducers
- A/D and D/A Converters
- Calibration Standards
- Instrumentation Reference

DESCRIPTION

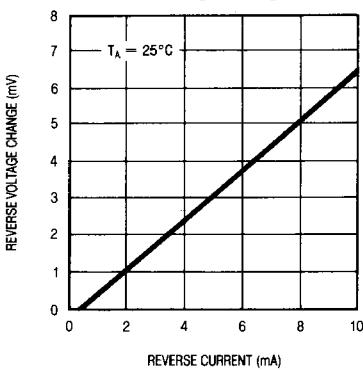
The LM129 temperature compensated 6.9 Volt zener references provide excellent stability over time and temperature, very low dynamic impedance and a wide operating current range. The device achieves low dynamic impedance by incorporating a high gain shunt regulator around the zener. The excellent noise performance of the device is achieved by using a "buried zener" design which eliminates surface noise phenomenon associated with ordinary zeners. To serve a wide variety of applications, the LM129 is available in several temperature coefficient grades and two package styles. A 20mA positive current source application is shown below.

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20mA Positive Current Source



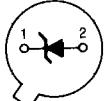
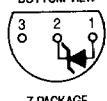
Reverse Voltage Change



ABSOLUTE MAXIMUM RATINGS

Reverse Breakdown Current.....	30mA
Forward Current.....	2mA
Operating Temperature Range	
LM129	-55°C to 125°C
LM329	0°C to 70°C
Storage Temperature Range	
LM129	-65°C to 150°C
LM329	-65°C to 150°C
Lead Temperature (Soldering, 10 sec.).....	300°C

PACKAGE/ORDER INFORMATION

	LM129AH LM329AH LM129BH LM329BH LM129CH LM329CH LM329DH
	LM329AZ LM329BZ LM329CZ LM329DZ

ELECTRICAL CHARACTERISTICS (See Note 1)

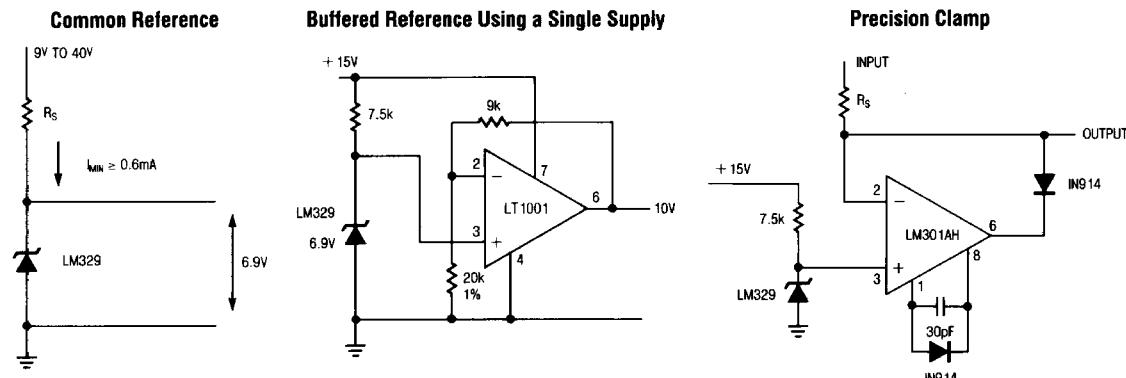
SYMBOL	PARAMETER	CONDITIONS	LM129A,B,C			LM329A,B,C,D			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V _Z	Reverse Breakdown Voltage	T _A = 25°C 0.6mA ≤ I _R ≤ 15mA	6.7	6.9	7.2	6.6	6.9	7.25	V
ΔV _Z ΔI _R	Reverse Breakdown Voltage Change with Current	T _A = 25°C 0.6mA ≤ I _R ≤ 15mA		9	14		9	20	mV
ΔV _Z ΔI _R	Reverse Breakdown Voltage Change with Current	1mA ≤ I _R ≤ 15mA	●	12			12		mV
ΔV _Z Δ Temp	Temperature Coefficient	I _R = 1mA LM129A/LM329A LM129B/LM329B LM129C/LM329C LM329D	● ● ● ●	6 15 30 50	10 20 50 100	6 15 30 50	10 20 50 100	ppm/°C ppm/°C ppm/°C ppm/°C	
	Change in Temperature Coefficient	1mA ≤ I _R ≤ 15mA	●	1			1		ppm/°C
r _Z	Dynamic Impedance (Note 2)	T _A = 25°C, I _R = 1mA (10Hz ≤ f ≤ 100Hz)		0.6	1		0.8	2	Ω
r _Z	Dynamic Impedance (Note 2)	1mA ≤ I _R ≤ 15mA (10Hz ≤ f ≤ 100Hz)	●	0.8			1		Ω
e _n	RMS Noise	T _A = 25°C, 10Hz ≤ f ≤ 10kHz		7	20		7	100	μV
ΔV _Z Δ Time	Long Term Stability	T _A = 45°C ± 0.1°C I _R = 1mA ± 0.3%		20			20		ppm/khr

The ● denotes the specifications which apply over full operating temperature range.

Note 1: These specifications apply over the full operating temperature range unless otherwise noted. To determine the junction temperature as a function of the ambient temperature, see θ_{JA} for each package.

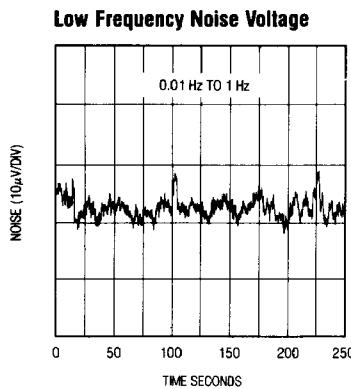
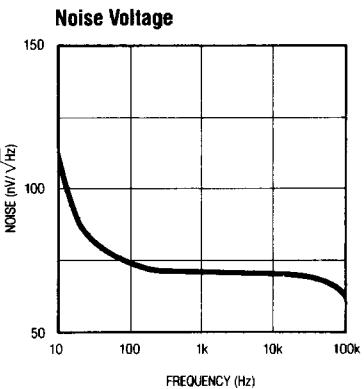
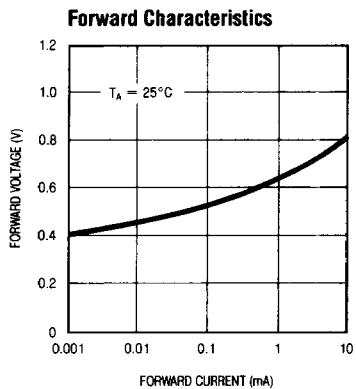
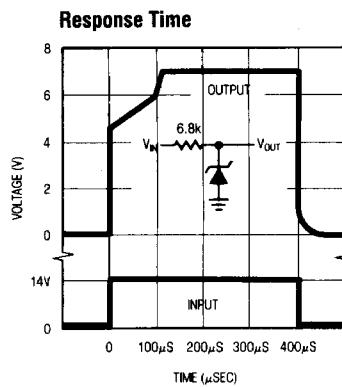
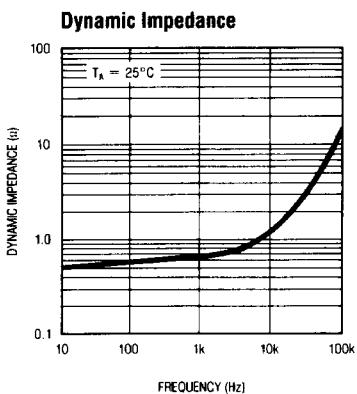
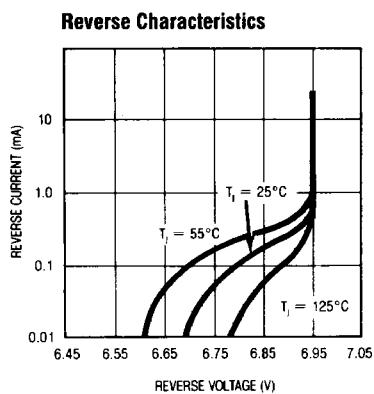
Note 2: Dynamic impedance guaranteed by "Reverse Breakdown Voltage Change with Current".

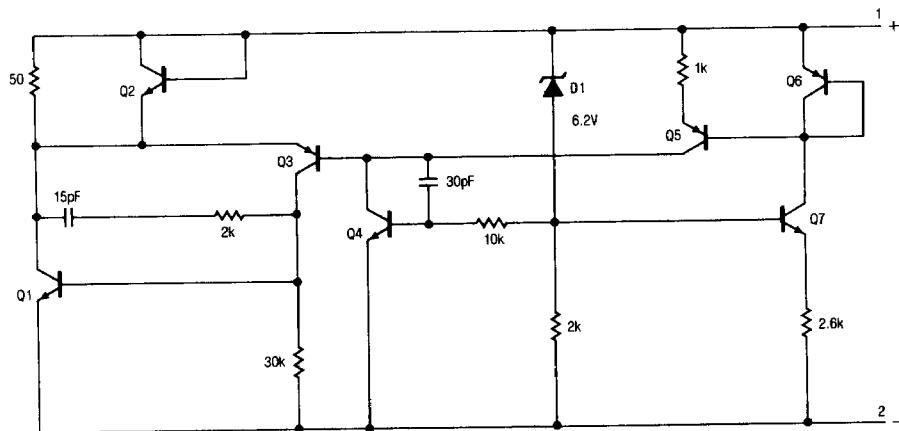
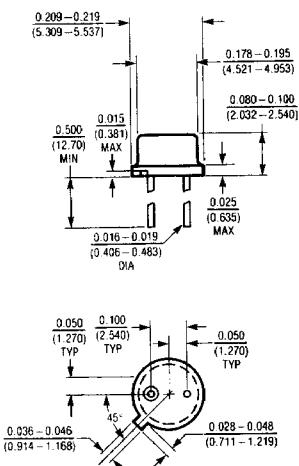
TYPICAL APPLICATIONS



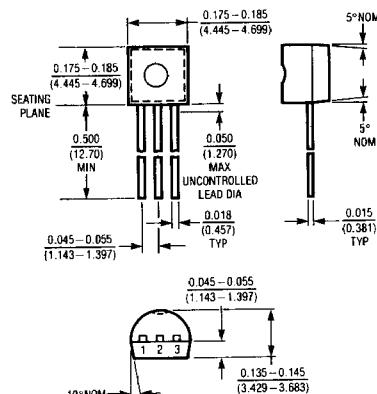
TYPICAL PERFORMANCE CHARACTERISTICS

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SCHEMATIC DIAGRAM**PACKAGE DESCRIPTION****H Package, 2 Lead TO-46 Metal Can**

$T_j\max$	θ_{ja}	θ_{jc}
150°C	440°C/W	80°C/W

Z Package, 3 Lead TO-92 Plastic

$T_j\max$	θ_{ja}
100°C	160°C/W